

Theory of Shielding and Gasketing

Fundamental Concepts

A knowledge of the fundamental concepts of EMI shielding will aid the designer in selecting the gasket inherently best suited to a specific design.

All electromagnetic waves consist of two essential components, a magnetic field, and an electric field. These two fields are perpendicular to each other, and the direction of wave propagation is at right angles to the plane containing these two components. The relative magnitude between the magnetic (H) field and the electric (E) field depends upon how far away the wave is from its source, and on the nature of the generating source itself. The ratio of E to H is called the wave impedance, Z_w .

If the source contains a large current flow compared to its potential, such as may be generated by a loop, a transformer, or power lines, it is called a current, magnetic, or low impedance source. The latter definition is derived from the fact that the ratio of E to H has a small value. Conversely, if the source operates at high voltage, and only a small amount of current flows, the source impedance is said to be high, and the wave is commonly referred to as an electric field. At very large distances from the source, the ratio of E to H is equal for either wave regardless of its origination. When this occurs, the wave is said to be a plane wave, and the wave impedance is equal to 377 ohms, which is the intrinsic impedance of free space. Beyond this point all waves essentially lose their curvature, and the surface containing the two components becomes a plane instead of a section of a sphere in the case of a point source of radiation.

The importance of wave impedance can be illustrated by considering what happens when an electromagnetic wave encounters a discontinuity. If the magnitude of the

wave impedance is greatly different from the intrinsic impedance of the discontinuity, most of the energy will be reflected, and very little will be transmitted across the boundary. Most metals have an intrinsic impedance of only milliohms. For low impedance fields (H dominant), less energy is reflected, and more is absorbed, because the metal is more closely matched to the impedance of the field. This is why it is so difficult to shield against magnetic fields. On the other hand, the wave impedance of electric fields is high, so most of the energy is reflected for this case.

Consider the theoretical case of an incident wave normal to the surface of a metallic structure as illustrated in Figure 1. If the conductivity of the metal wall is infinite, an electric field equal and opposite to that of the incident electric field components of the wave is generated in the shield. This satisfies the boundary condition that the total tangential electric field must vanish at the boundary. Under these ideal conditions, shielding should be perfect because the two fields exactly cancel one another. The fact that the magnetic fields are in phase means that the current flow in the shield is doubled.

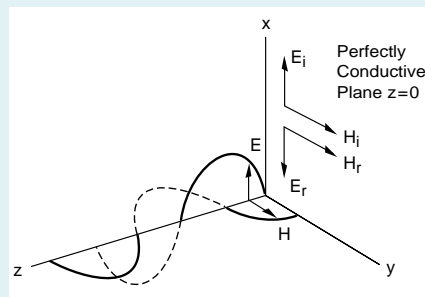


Figure 1 Standard Wave Pattern of a Perfect Conductor Illuminated by a Normally Incident, + X Polarized Plane Wave

Shielding effectiveness of metallic enclosures is not infinite, because the conductivity of all metals is finite. They can, however, approach very large values. Because metallic shields have less than infinite conductivity, part of the field is

transmitted across the boundary and supports a current in the metal as illustrated in Figure 2. The amount of current flow at any depth in the shield, and the rate of decay is governed by the conductivity of the metal and its permeability. The residual current appearing on the opposite face is the one responsible for generating the field which exists on the other side.

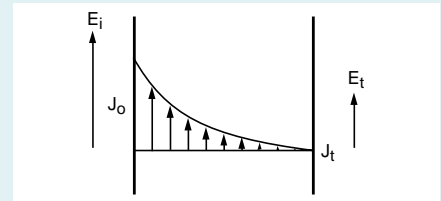


Figure 2 Variation of Current Density with Thickness for Electrically Thick Walls

Our conclusion from Figures 2 and 3 is that thickness plays an important role in shielding. When skin depth is considered, however, it turns out that thickness is only critical at low frequencies. At high frequencies, even metal foils are effective shields.

The current density for thin shields is shown in Figure 3. The current density in thick shields is the same as for thin shields. A secondary reflection occurs at the far side of the shield for all thicknesses. The only difference with thin shields is that a large part of the re-reflected wave may appear on the front surface. This wave can add to or subtract from the primary reflected wave depending upon the phase relationship between them. For this reason, a correction factor appears in the shielding calculations to account for reflections from the far surface of a thin shield.

A gap or slot in a shield will allow electromagnetic fields to radiate through the shield, unless the current continuity can be preserved across the gaps. The function of an EMI gasket is to preserve continuity of current flow in the shield. If the gasket is made of a material identical to the walls of the shielded

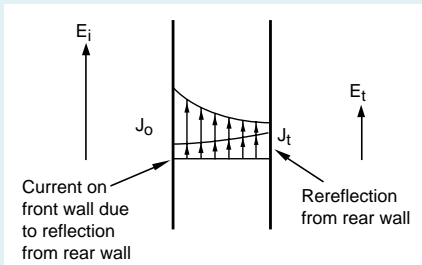


Figure 3 Variation of Current Density with Thickness for Electrically Thin Wall enclosure, the current distribution in the gasket will also be the same assuming it could perfectly fill the slot. (This is not possible due to mechanical considerations.)

The flow of current through a shield including a gasket interface is illustrated in Figure 4. Electromagnetic leakage through the seam can occur in two ways. First, the energy can leak through the material directly. The gasket material shown in Figure 4 is assumed to have lower conductivity than the material in the shield. The rate of current decay, therefore, is also less in the gasket. It is apparent that more current will

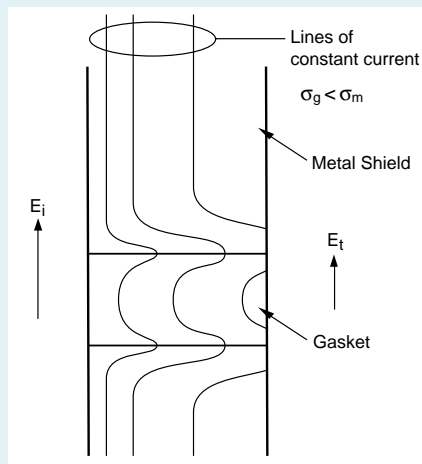


Figure 4 Lines of Constant Current Flow Through a Gasketed Seam

appear on the far side of the shield. This increased flow causes a larger leakage field to appear on the far side of the shield. Second, leakage can occur at the interface between the gasket and the shield. If an air

gap exists in the seam, the flow of current will be diverted to those points or areas which are in contact. A change in the direction of the flow of current alters the current distribution in the shield as well as in the gasket. A high resistance joint does not behave much differently than open seams. It simply alters the distribution of current somewhat. A current distribution for a typical seam is shown in Figure 4. Lines of constant current flow spaced at larger intervals indicate less flow of current.

It is important in gasket design to make the electrical properties of the gasket as similar to the shield as possible, maintain a high degree of electrical conductivity at the interface, and avoid air, or high resistance gaps.

Shielding and Gasket Equations¹

The previous section was devoted to a physical understanding of the fundamental concepts of shielding and gasketing. This section is devoted to mathematical expressions useful for general design purposes. It is helpful to understand the criteria for selecting the parameters of a shielded enclosure.

In the previous section, it was shown that electromagnetic waves incident upon a discontinuity will be partially reflected, and partly transmitted across the boundary and into the material. The effectiveness of the shield is the sum total of these two effects, plus a correction factor to account for reflections from the back surfaces of the shield. The overall expression for shielding effectiveness is written as:

$$S.E. = R + A + B \quad (1)$$

where

S.E. is the shielding effectiveness² expressed in dB,

R is the reflection factor expressed in dB,

A is the absorption term expressed in dB, and

B is the correction factor due to reflections from the far boundary expressed in dB.

The reflection term is largely dependent upon the relative mismatch between the incoming wave and the surface impedance of the shield. Reflection terms for all wave types have been worked out by others.³ The equations for the three principal fields are given by the expressions:

$$R_E = 353.6 + 10 \log_{10} \frac{G}{f^3 \mu r_1^2} \quad (2)$$

$$R_H = 20 \log_{10} \left(0.462 \sqrt{\frac{\mu}{Gf}} + 0.136 r_1 \sqrt{\frac{fG}{\mu}} + 0.354 \right) \quad (3)$$

$$R_P = 108.2 + 10 \log_{10} \frac{G \times 10^6}{\mu f} \quad (4)$$

where

R_E , R_H , and R_P are the reflection terms for the electric, magnetic, and plane wave fields expressed in dB.

G is the relative conductivity referred to copper,

f is the frequency in Hz,

μ is the relative permeability referred to free space,

r_1 is the distance from the source to the shield in inches.

The absorption term A is the same for all three waves and is given by the expression:

$$A = 3.338 \times 10^{-3} \times t \sqrt{\mu f G} \quad (5)$$

where

A is the absorption or penetration loss expressed in dB, and t is the thickness of the shield in mils.

The factor B can be mathematically positive or negative (in practice it is always negative), and becomes insignificant when $A > 6$ dB. It is usually only important when metals are thin, and at low frequencies (i.e., below approximately 20 kHz).

$$B \text{ (in dB)} = 20 \log_{10} \quad (6)$$

$$\left| 1 - \left(\frac{K-1}{K+1} \right)^2 \right| \left(10^{-A/10} \right) \left(e^{-j227A} \right)$$

where

A = absorption losses (dB)

$$|K| = |Z_s/Z_H| = 1.3(\mu/fr^2G)^{1/2}$$

Z_s = shield impedance

Z_H = impedance of the incident magnetic field

References

- Much of the analysis discussed in this section was performed by Robert B. Cowdell, as published in "Nomograms Simplify Calculations of Magnetic Shielding Effectiveness" EDN, page 44, September 1, 1972.
- Shielding Effectiveness is used in lieu of absorption because part of the shielding effect is caused by reflection from the shield, and as such is not an absorption type loss.
- Vasaka, G.J., *Theory, Design and Engineering Evaluation of Radio-Frequency Shielded Rooms*, U.S. Naval Development Center, Johnsville, Pa., Report NADC-EL-54129, dated 13 August, 1956.

The preceding equation was solved in two parts. A digital computer was programmed to solve for B with a preselected value of A, while $|K|$ varied between 10^{-4} and 10^3 . The results are plotted in Figure 9.

The nomograph shown in Figure 8 was designed to solve for $|K|$ in equation (6). Note that when Z_H becomes much smaller than Z_S ($K > 1$), large positive values of B may result. These produce very large and unrealistic computed values of S.E., and imply a low frequency limitation on the B equation. In practical cases, absorption losses (A) must be calculated before B can be obtained.¹

A plot of reflection and absorption loss for copper and steel is shown in Figure 5. This illustration gives a good physical representation of the behavior of the component parts of an electromagnetic wave. It also illustrates why it is so much more difficult to shield magnetic fields than electric fields or plane waves. Note: In Figure 5, copper offers more shielding effectiveness than steel in all cases except for absorption loss. This is due to the high permeability of iron. These shielding numbers are theoretical, hence they are very high (and unrealistic) practical values.

If magnetic shielding is required, particularly at frequencies below 14 kHz, it is customary to neglect all terms in equation (1) except the absorption term A. Measurements of numerous shielded enclosures bears this out. Conversely, if only electric field, or plane wave protection is required, reflection is the important factor to consider in the design.

The effects of junction geometry, contact resistance, applied force and other factors which affect gasket performance are discussed in the design section which follows.

Polarization Effects

Currents induced in a shield flow essentially in the same direction as the electric field component of the inducing wave. For example, if the electric component of a wave is vertical, it is known as a vertically polarized wave, and it will cause a

current to flow in the shield in a vertical direction. A gasket placed transverse to the flow of current is less effective than one placed parallel to the flow of current.

A circularly polarized wave contains equal vertical and horizontal components, so gaskets must be equally effective in both directions. Where polarization is unknown, gasketed junctions must be designed and tested for the worse condition; that is, where the flow of current is parallel to the gasket seam.

Nomographs

The nomographs presented in Figures 6 through 9 will aid the designer in determining absorption and magnetic field reflection losses directly¹. These nomographs are based on the equations described in the previous section.

Absorption Loss – Figure 6:

Given a desired amount of absorption loss at a known frequency, determine the required thickness for a known metal:

- Locate the frequency on the f scale and the desired absorption loss on the A scale.

Place a straight-edge across these points and locate a point on the unmarked X scale
(*Example: A = 10 dB, f = 100 kHz*).

- Pivot the straight-edge about the point on the unmarked X scale to various metals noted on the $G \times \mu$ scale. A line connecting the $G \times \mu$ scale and the point on the unmarked scale will give the required thickness on the t scale.
(*Example: for copper t = 9.5 mils, cold rolled steel t = 2.1 mils*).

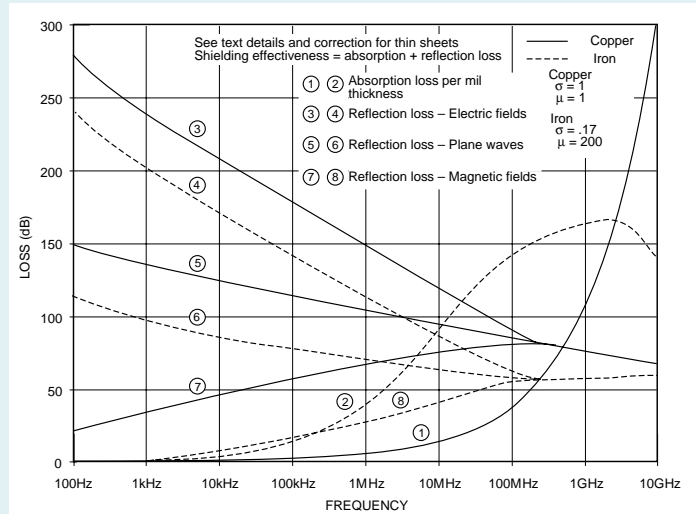


Figure 5 Shielding Effectiveness of Metal Barriers

Some care must be exercised in using these charts for ferrous materials because μ varies with magnetizing force.

Magnetic Field Reflection –

Figure 7: To determine magnetic field reflection loss R_H :

- Locate a point on the G/μ scale for one of the metals listed. If the metal is not listed, compute G/μ and locate a point on the numerical scale.
- Locate the distance between the energy source and the shield on the r scale.
- Place a straight-edge between r and G/μ and locate a point on the unmarked X scale
(*Example: r = 10 inches for hot rolled steel*).
- Place a straight-edge between the point on the X scale and the desired frequency on the f scale.
- Read the reflection loss from the R_H scale. (For $f = 10$ kHz, $R_H = 13$ dB).
- By sweeping the f scale while holding the point on the X scale, R_H versus frequency can be obtained. (For $f = 1$ kHz, $R_H = 3.5$ dB).

(Note that thickness is not a factor in calculating reflection losses.)

References

- Robert B. Cowdell, "Nomograms Simplify Calculations of Magnetic Shielding Effectiveness" **EDN**, page 44, September 1, 1972.

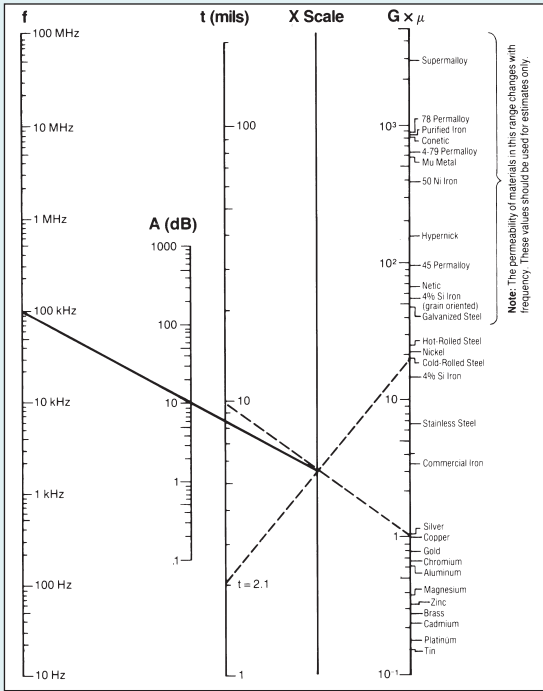


Figure 6 Absorption Loss Nomograph¹

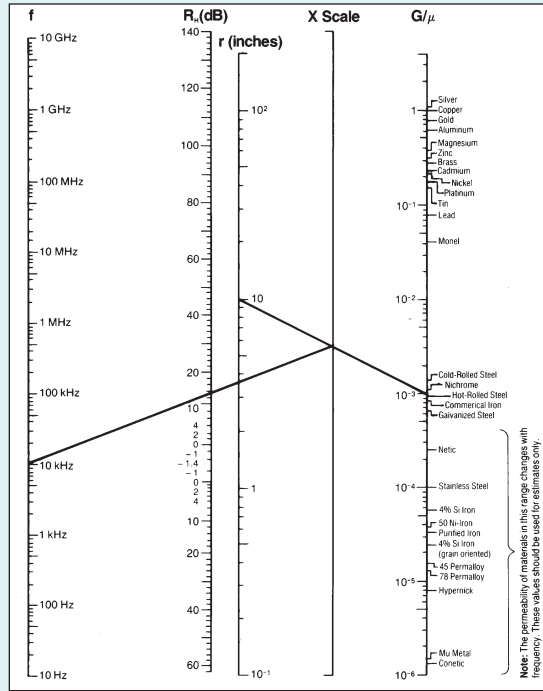


Figure 7 Magnetic Field Reflection Loss Nomograph, R_H ¹

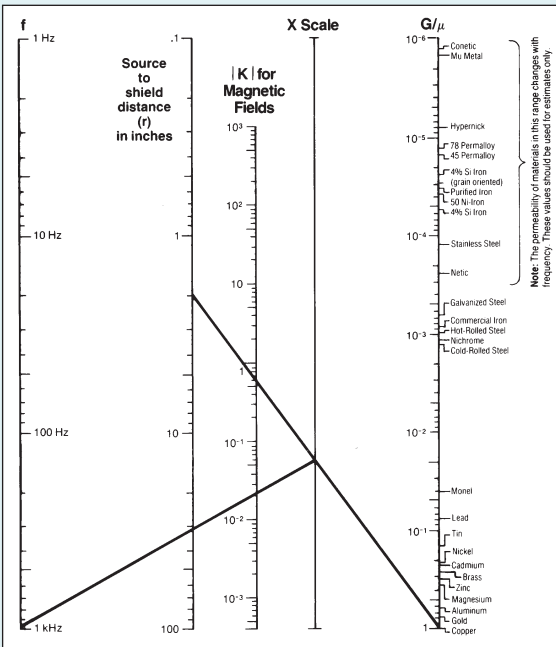


Figure 8 Magnetic Field Secondary Reflection Loss Factor Nomograph¹

Magnetic Field Secondary Reflection Losses |K| Figures 8 and 9:

To determine the magnetic field secondary reflection loss factor |K| to solve for B:

Given: $r = 2$ inches for 0.0162 in. thick copper and $A = 1.3$ dB.

Find B at 1 kHz.

- Draw a line between copper on the G/μ scale and $r = 2$ inches on the "source to shield distance scale." Locate a point on the X scale.
- Draw a line from the point on the X scale to 1 kHz on the f scale.
- At its intersection with the |K| scale, read $|K| = 2.2 \times 10^{-2}$.
- Proceed to Figure 9.
- On Figure 9, locate $|K| = 2.2 \times 10^{-2}$ on the horizontal scale.
- Move vertically to intersect the $A = 1.3$ curve (interpolate), and then horizontally to find $B = -8.5$ dB.

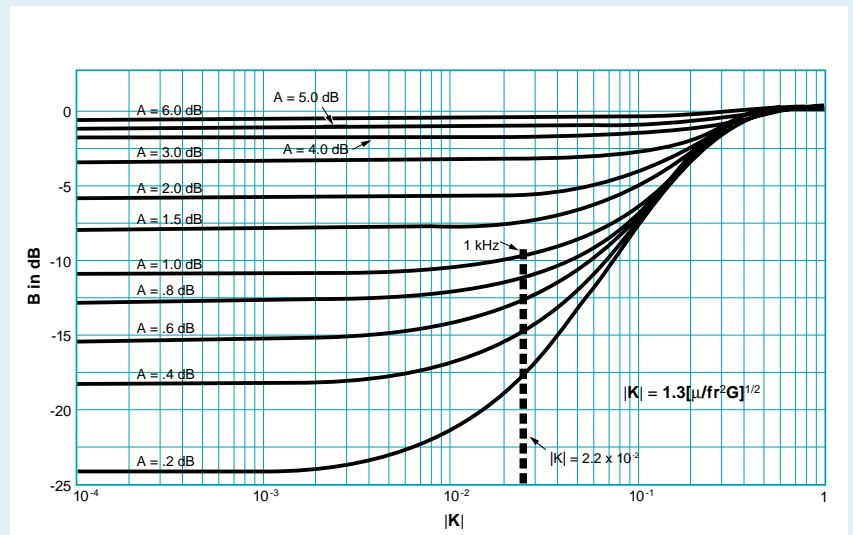


Figure 9 Solving for Secondary Reflection Loss (B)¹